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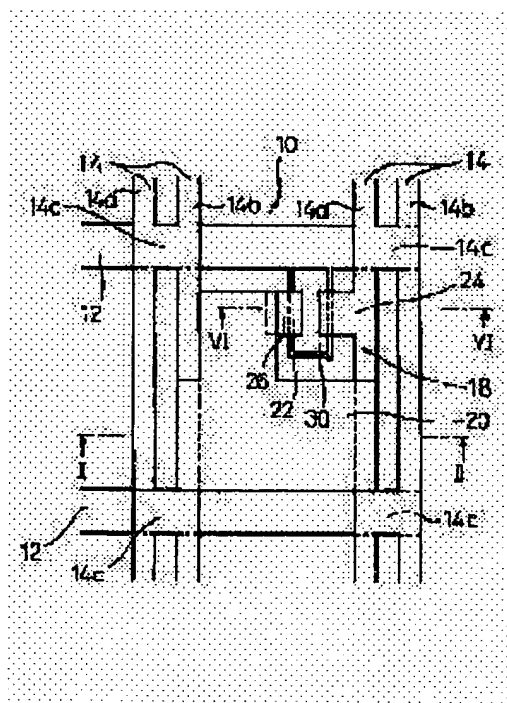
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## (54) THIN FILM TRANSISTOR SUBSTRATE AND ITS MANUFACTURE

### (57)Abstract:

PURPOSE: To obtain high aperture rate in the case of being used in a display device.

CONSTITUTION: A thin film transistor has a gate bus line 12 formed on an insulated plate; a drain bus line 14 arranged so as to cross the gate bus line 12 through an insulating layer; a thin film transistor 18 provided at every crossing part between the gate bus line 12 and the drain bus line 14; and a picture element electrode 20 connected to the thin film transistor 18, and each drain bus line 14 is composed of two drain bus line parts 14a, 14b extending in parallel to each other, and the picture element electrode 20 is overlappingly provided on the drain bus line part 14a on its one side and the drain bus line part 14b on its other side.



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